onsemi

Low Voltage Comparator FAN156

Description

The FAN156 is a low–power single comparator that typically consumes less than 10 μ A of supply current. It is guaranteed to operate at a low voltage of 1.6 V and is fully operational up to 5.5 V, making it convenient for use in 1.8, 3.0 V, and 5.0 V systems.

The FAN156 has a complementary push–pull P– and N–channel output stage capable of driving a rail–to–rail output swing with a load ranging up to 5.0 mA.

Features

- Low Supply Current: I_{DD} 6 µA (Typical)
- Single Power Supply Operation
- Wide Common–Mode Input Voltage Range
- Push–Pull Output Circuit
- Low Input Bias Current
- Internal Hysteresis
- Packaged in MicroPak[™] 6
- This is a Pb–Free Device

Applications

- Mobile Phones
- Alarm and Security Systems
- Personal Digital Assistants

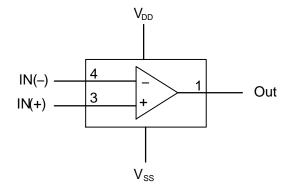


Figure 1. Functional Diagram



SIP6 1.45x1.0 CASE 127EB

MARKING DIAGRAM

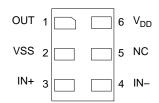


- CN = Specific Device Code
- &K = 2-Digits Lot Run Traceability Code
- &2 = 2–Digit Date Code
- &Z = Assembly Plant Code

ORDERING INFORMATION

See detailed ordering and shipping information on page 7 of this data sheet.

PIN CONFIGURATION





PIN DEFINITIONS

Pin #	Name	Description
1	OUT	Comparator Output
2	V _{SS}	Negative Supply Voltage
3	IN+	Non–Inverting Input
4	IN–	Inverting Input
5	NC	No Connect
6	V _{DD}	Positive Supply Voltage

FUNCTION TABLE

Inputs	Outputs
IN(-) > IN(+)	Output LOW
IN(+) > IN(-)	Output HIGH

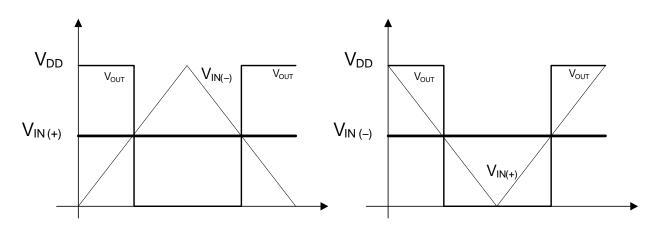


Figure 3. V_{IN} vs. V_{OUT}

ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Condition	Min.	Max.	Unit
V_{DD} to V_{SS}	Supply Voltage		-3.0	+3.0	V
			0	6.0	
DVIN	Differential Input Voltage			±6	
V _{IN}	Input Voltage			V_{SS} to V_{DD}	V
ts	Output Short Circuit Duration (Note 1)			Indefinite	S
ТJ	Junction Temperature			+150	°C
T _{STG}	Storage Temperature Range		-65	+150	°C
PD	Power Dissipation			194	mW
Θ_{JA}	Thermal Resistance			335	°C/W
ESD	IEC 61000-4-2 System ESD	Air Gap		15	kV
		Contact		8	
	JEDEC JESD22-A114, Human Body	All Pins		8	
	Model	Pin to Pin: IN(–), IN(+) to V _{DD} or VSS		12	1
	JEDEC JESD22–C101, Charged Device Model	All Pins		2	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected. 1. The maximum total power dissipation must not be exceeded.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Condition	Min.	Max.	Unit
V_{DD} to V_{SS}	Power Supply		-2.75	+2.75	V
			0	5.50	
V _{DD}	Power Supply	V _{SS} 0 V	1.6	5.5	V
V _{IN}	Input Voltage			$\rm V_{SS}$ to $\rm V_{DD}$	V
I _{OH} /I _{OL}	Output Sink/Source Current	V _{DD} 5.0 V		5	mA
		V _{DD} 3.0 V		3	
		V _{DD} 1.6 V		1	
T _A	Operating Temperature, Free Air		-40	+85	°C

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Condition	Min.	Тур.	Max.	Unit
V _{DD} = 5.5 V, V	$T_{SS} = GND$, and $T_A = +25^{\circ}C$					
V _{HYS}	Input Hysteresis	$V_{CM} = 0.5 V_{DD}$		4		mV
V _{IO}	Input Offset Voltage (Note 2)	$V_{CM} = 0.5 V_{DD}$	–15	±1	+15	mV
I _{IO}	Input Offset Current			10		pА
lı	Input Bias Current			10		pА
V _{CM}	Common Mode Input Voltage		V _{SS}		V _{DD}	V
CMRR	Common Mode Rejection Ratio (Note 3)	$V_{CM} = V_{DD}$		68		dB
I _{DD}	Supply Current			6	17	μΑ
PSRR	Power Supply Rejection Ratio (Note 3)	$\Delta V_{DD} = 0.5 V$	45	80		dB
I _{OS}	Output Short Circuit Current	$V_{O} = V_{DD}$		60		mA
		$V_{O} = V_{SS}$		90		
V _{OL}	Low-Level Output Voltage	I _{SINK} = 5.0 mA		0.1	0.3	V
V _{OH}	High-Level Output Voltage	I _{SOURCE} = 5.0 mA	5.2	5.4		V
t _{PLH}	Propagation Delay (Turn–On)	Overdrive 20 mV, $C_L = 15 \text{ pF}$		0.40		μS
t _{PHL}	Propagation Delay (Turn–Off)	Overdrive = 20 mV, $C_L = 15 \text{ pF}$		0.42		μs
t _{TLH}	Response Time, Output Rise/Fall	C _L = 50 pF		4.0		ns
t _{THL}	(Note 4)			5.4		
/ _{DD} = 3 V, V _S	_S = GND, and T _A = +25°C	•	•			
V _{HYS}	Input Hysteresis	$V_{CM} = 0.5 V_{DD}$		4		mV
V _{IO}	Input Offset Voltage (Note 2)	$V_{CM} = 0.5 V_{DD}$	-15	±1	+15	mV
I _{IO}	Input Offset Current			10		pА
l	Input Bias Current			10		pА
V _{CM}	Common Mode Input Voltage		V _{SS}		V _{DD}	V
CMRR	Common Mode Rejection Ratio (Note 3)	$V_{CM} = V_{DD}$		60		dB
I _{DD}	Supply Current			5.5	15.0	μΑ
PSRR	Power Supply Rejection Ratio (Note 3)	$\Delta V_{DD} = 0.5 V$	45	80		dB
I _{OS}	Output Short Circuit Current	$V_{O} = V_{DD}$		27		mA
		$V_{O} = V_{SS}$		35		
V _{OL}	Low-Level Output Voltage	I _{SINK} = 3.0 mA		0.15	0.35	V
V _{OH}	High-Level Output Voltage	I _{SOURCE} = 3.0 mA	2.65	2.85		V
t _{PLH}	Propagation Delay (Turn-On)	Overdrive = 20 mV, $C_L = 15 \text{ pF}$		0.45		μs
t _{PHL}	Propagation Delay (Turn–Off)	Overdrive = 20 mV, $C_L = 15 \text{ pF}$		0.47		μs
t _{TLH}	Response Time, Output Rise/Fall (Note 4)			6.1	1	ns
t _{THL}	1			6.2		
	$I_{SS} = GND$, and $T_A = +25^{\circ}C$	•	-			-
V _{HYS}	Input Hysteresis	$V_{CM} = 0.5 V_{DD}$		3.5		mV
V _{IO}	Input Offset Voltage (Note 2)	$V_{CM} = 0.5 V_{DD}$	-15	±1	+15	mV
l _{IO}	Input Offset Current			10		pА
I	Input Bias Current			10		рА
V _{CM}	Common Mode Input Voltage		V _{SS}		V _{DD}	V
CMRR	Common Mode Rejection Ratio (Note 3)	V _{CM} = V _{DD}		56		dB

ELECTRICAL CHARACTERISTICS (continued)

Symbol	Parameter	Condition	Min.	Тур.	Max.	Unit
V _{DD} = 1.6 V, V	_{SS} = GND, and T _A = +25°C					
I _{DD}	Supply Current			5	15	μΑ
PSRR	Power Supply Rejection Ratio (Note 3)	$\Delta V_{DD} = 0.5 V$	45	80		dB
I _{OS}	Output Short Circuit Current	$V_{O} = V_{DD}$		5.5		mA
		$V_{O} = V_{SS}$		7.5		
V _{OL}	Low-Level Output Voltage	I _{SINK} = 5.0 mA		0.10	0.25	V
V _{OH}	High-Level Output Voltage	I _{SOURCE} = 5.0 mA	1.35	1.50		V
t _{PLH}	Propagation Delay (Turn–On)	Overdrive 20 mV, $C_L = 15 \text{ pF}$		0.52		μS
t _{PHL}	Propagation Delay (Turn–Off)	Overdrive = 20 mV, $C_L = 15 \text{ pF}$		0.54		μs
t _{TLH}	Response Time, Output Rise/Fall	C _L = 50 pF		16.5		ns
t _{THL}	(Note 4)			13.0]

Differential input switching level is guaranteed at the minimum or maximum offset voltage, minus or plus half the maximum hysteresis voltage.
Guaranteed by design and characterization data.
Input signal: 1 kHz, square-wave signal with 10 ns edge rate.

TYPICAL PERFORMANCE CHARACTERISTICS

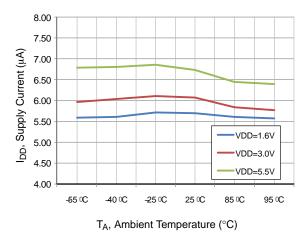


Figure 4. Supply Current vs. Temperature

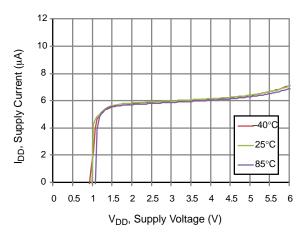


Figure 6. Supply Current vs. Supply Voltage

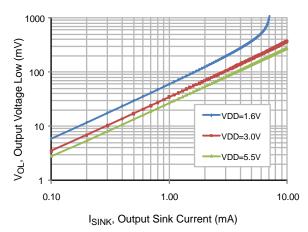


Figure 8. Output LOW vs. Output Drive Current

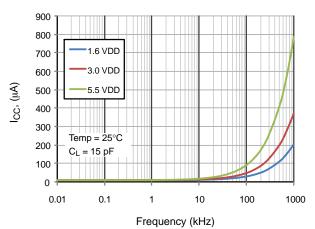


Figure 5. Supply Current vs. Output

Transition Frequency

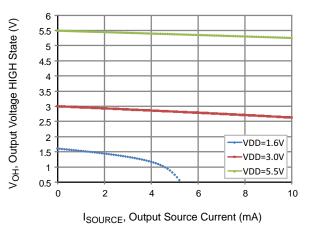
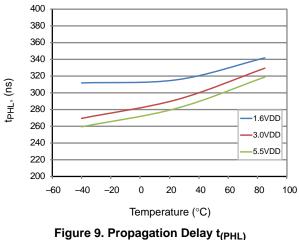
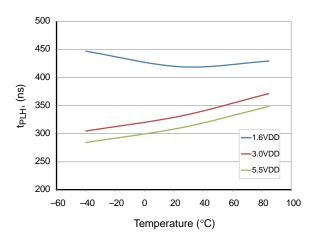


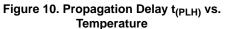
Figure 7. Output HIGH vs. Output Drive Current





TYPICAL PERFORMANCE CHARACTERISTICS (continued)





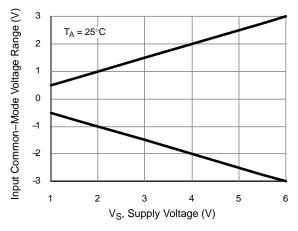


Figure 12. Input Common–Mode Voltage Range vs. Supply Voltage

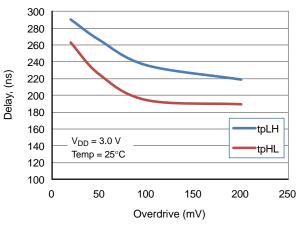


Figure 11. Propagation Delay vs. Input Overdrive

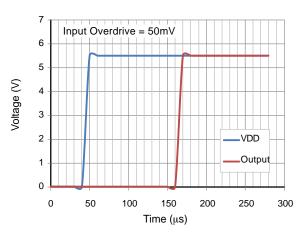


Figure 13. Power–Up Delay

ORDERING INFORMATION

Device	Operating Temperature Range	Top Mark	Package	Shipping [†]
FAN156L6X	–40°C to +85°C	CN	6–Lead, SIP6 1.45x1.0 (MicroPak [™]) (Pb–Free)	5000 / Tape & Reel

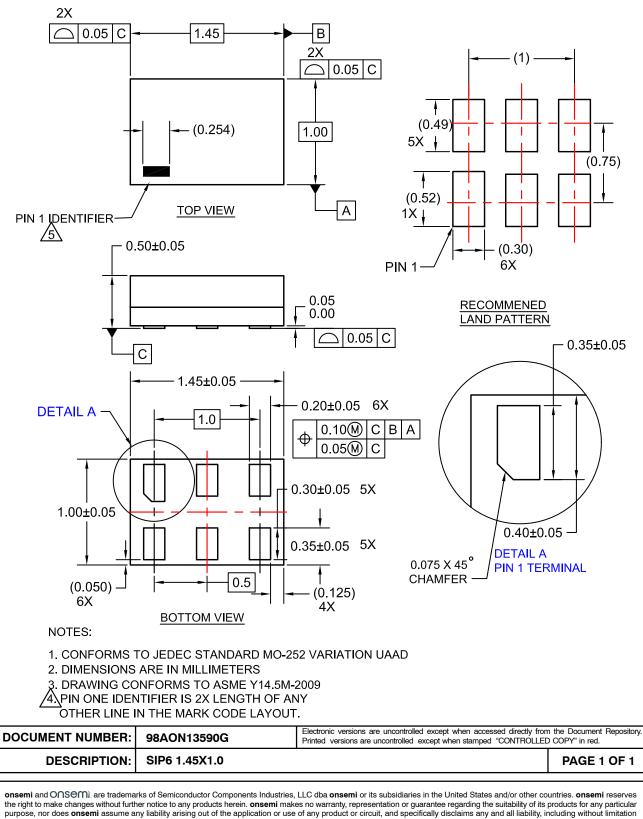
+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

MicroPak is a trademark of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries.



SIP6 1.45X1.0 CASE 127EB ISSUE O

DATE 31 AUG 2016



special, consequential or incidental damages. onsemi does not convey any license under its patent rights nor the rights of others.

onsemi, ONSEMI, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi's product/patent coverage may be accessed at <u>www.onsemi.com/site/pdf/Patent_Marking.pdf</u>. onsemi reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and onsemi makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or indental damages. Buyer is responsible for its products and applications using onsemi products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by onsemi. "Typical" parameters which may be provided in onsemi data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. onsemi does not convey any license under any of its intellectual property rights nor the rights of others. onsemi products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification. Buyer shall indemnify and hold onsemi and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs,

ADDITIONAL INFORMATION

TECHNICAL PUBLICATIONS:

Technical Library: www.onsemi.com/design/resources/technical-documentation onsemi Website: www.onsemi.com

ONLINE SUPPORT: <u>www.onsemi.com/support</u> For additional information, please contact your local Sales Representative at <u>www.onsemi.com/support/sales</u>